

Sample &

Buv





SLVSC42A - AUGUST 2013 - REVISED APRIL 2015

TPS22967 Single-Channel, Ultra-Low Resistance Load Switch

Technical

Documents

1 Features

- Integrated Single-Channel Load Switch
- Input Voltage Range: 0.8 V to 5.5 V
- Low RON Resistance
 - R_{ON} = 22 m Ω at V_{IN} = 5 V (V_{BIAS} = 5 V)
 - $R_{ON} = 22 \text{ m}\Omega \text{ at } V_{IN} = 3.6 \text{ V} (V_{BIAS} = 5 \text{ V})$
 - R_{ON} = 22 m Ω at V_{IN} = 1.8 V (V_{BIAS} = 5 V)
- 4-A Maximum Continuous Switch Current
- Low Quiescent Current (50 µA)
- Low Control Input Threshold Enables Use of 1.2-V, 1.8-V, 2.5-V, and 3.3-V Logic
- Configurable Rise Time
- Quick Output Discharge (QOD)
- WSON 8-Pin Package With Thermal Pad

Applications 2

- Ultrabooks™
- Notebooks and Netbooks
- **Tablet PCs**
- **Consumer Electronics**
- Set-Top Boxes and Residental Gateways
- **Telecom Systems**
- Solid-State Drives (SSD)

Typical Application Schematic

3 Description

Tools &

Software

The TPS22967 device is a small, ultra-low R_{ON}, single-channel load switch with controlled turnon. The device contains an N-channel MOSFET that can operate over an input voltage range of 0.8 V to 5.5 V and can support a maximum continuous current of 4 A. The switch is controlled by an on/off input (ON), which can interface directly with low-voltage control signals. In the TPS22967, a 225-Ω pulldown resistor is added for quick output discharge when the switch is turned off.

Support &

Community

20

The TPS22967 is available in a small, space-saving 2-mm × 2-mm 8-pin WSON package (DSG) with integrated thermal pad allowing for high power dissipation. The device is characterized for operation over the free-air temperature range of -40°C to 85°C.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|-------------|----------|-------------------|
| TPS22967 | WSON (8) | 2.00 mm × 2.00 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

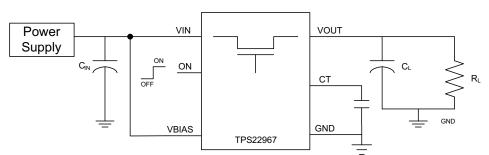




Table of Contents

| 1 | Feat | ures 1 |
|---|------|--|
| 2 | Арр | lications 1 |
| 3 | Des | cription 1 |
| 4 | Турі | cal Application Schematic 1 |
| 5 | Rev | ision History 2 |
| 6 | | Configuration and Functions 3 |
| 7 | Spe | cifications 4 |
| | 7.1 | Absolute Maximum Ratings 4 |
| | 7.2 | ESD Ratings 4 |
| | 7.3 | Recommended Operating Conditions 4 |
| | 7.4 | Thermal Information 5 |
| | 7.5 | Electrical Characteristics: V _{BIAS} = 5 V5 |
| | 7.6 | Electrical Characteristics: V _{BIAS} = 2.5 V6 |
| | 7.7 | Switching Characteristics |
| | 7.8 | Typical Characteristics 8 |
| 8 | Deta | ailed Description 14 |

5 Revision History

Changes from Original (August 2013) to Revision A

Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device



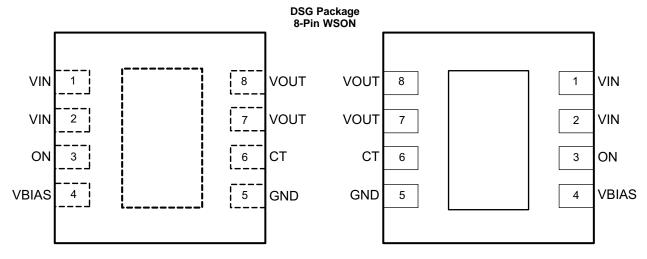
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Page

| | 8.1 | Overview |
|----|------|-----------------------------------|
| | 8.2 | Functional Block Diagram 14 |
| | 8.3 | Feature Description 14 |
| | 8.4 | Device Functional Modes 15 |
| 9 | App | lication and Implementation 16 |
| | 9.1 | Application Information |
| | 9.2 | Typical Application |
| 10 | Pow | ver Supply Recommendations 19 |
| 11 | Lay | out 19 |
| | | Layout Guidelines 19 |
| | | Layout Example 20 |
| 12 | Dev | ice and Documentation Support |
| | 12.1 | Trademarks 20 |
| | 12.2 | Electrostatic Discharge Caution |
| | 12.3 | Glossary 20 |
| 13 | Mec | hanical, Packaging, and Orderable |
| | Info | mation |



6 Pin Configuration and Functions



TOP VIEW

BOTTOM VIEW

Pin Functions

| PIN | | 1/0 | DESCRIPTION | | | |
|-------------|------|-----|--|--|--|--|
| NAME | NO. | 1/0 | DESCRIPTION | | | |
| CT 6 | | 0 | Switch slew rate control. Can be left floating. See <i>Application and Implementation</i> for more information. | | | |
| GND | 5 | - | Device ground. | | | |
| ON | 3 | I | Active high switch control input. Do not leave floating. | | | |
| VBIAS | 4 | I | Bias voltage. Power supply to the device. Recommended voltage range for this pin is 2.5 V to 5.5 V. See Application Information section for more information. | | | |
| VIN | 1, 2 | I | Switch input. Input capacitor recommended for minimizing V _{IN} dip. Recommended voltage range for this pin for optimal R _{ON} performance is 0.8 V to V _{BIAS} . | | | |
| VOUT | 7, 8 | 0 | Switch output. | | | |
| Thermal Pad | | - | Thermal pad (exposed center pad) to alleviate thermal stress. Tie to GND. See <i>Layout Example</i> for layout guidelines. | | | |

7 Specifications

7.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)⁽¹⁾⁽²⁾

| | | MIN | MAX | UNIT ⁽²⁾ |
|-------------------|---|------|-----|---------------------|
| V _{IN} | Input voltage | -0.3 | 6 | V |
| V _{OUT} | Output voltage | -0.3 | 6 | V |
| V _{BIAS} | Bias voltage | -0.3 | 6 | V |
| V _{ON} | ON voltage | -0.3 | 6 | V |
| I _{MAX} | Maximum continuous switch current | | 4 | А |
| I _{PLS} | Maximum pulsed switch current, pulse <300 µs, 2% duty cycle | | 6 | А |
| T _A | Operating free-air temperature ⁽³⁾ | -40 | 85 | °C |
| TJ | Maximum junction temperature | | 125 | °C |
| T _{LEAD} | Maximum lead temperature (10-s soldering time) | | 300 | °C |
| T _{STG} | Storage temperature | -65 | 150 | °C |

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

(3) In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature may have to be derated. Maximum ambient temperature $[T_{A(max)}]$ is dependent on the maximum operating junction temperature $[T_{J(max)}]$, the maximum power dissipation of the device in the application $[P_{D(max)}]$, and the junction-to-ambient thermal resistance of the part/package in the application (θ_{JA}), as given by the following equation: $TA_{(max)} = T_{J(max)} - (\theta_{JA} \times P_{D(max)})$.

7.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|---|-------|------|
| | | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | |
| V _(ESD) | Electrostatic discharge | Charged device model (CDM), per JEDEC specification JESD22-C101 $^{\left(2\right) }$ | ±1000 | V |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

| | | | MIN | NOM MAX | UNIT |
|-------------------|---------------------------------|------------------------------------|------------------|-------------------|------|
| V _{IN} | Input voltage | | 0.8 | V _{BIAS} | V |
| V _{BIAS} | Bias voltage | | 2.5 | 5.5 | V |
| V _{ON} | ON voltage | | 0 | 5.5 | V |
| V _{OUT} | Output voltage | | | V _{IN} | V |
| V _{IH} | High-level input voltage, ON | V _{BIAS} = 2.5 V to 5.5 V | 1.2 | 5.5 | V |
| V _{IL} | Low-level input voltage, ON | V _{BIAS} = 2.5 V to 5.5 V | 0 | 0.5 | V |
| C _{IN} | Input capacitor | | 1 ⁽¹⁾ | | μF |

(1) Refer to Application Information.

7.4 Thermal Information

| | | TPS22967 | |
|-----------------------|--|------------|------|
| | THERMAL METRIC ⁽¹⁾ | DSG [WSON] | UNIT |
| | | 8 PINS | |
| R_{\thetaJA} | Junction-to-ambient thermal resistance | 65.3 | |
| R _{0JC(top)} | Junction-to-case (top) thermal resistance | 74.2 | |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 35.4 | °C/W |
| Ψ _{JT} | Junction-to-top characterization parameter | 2.2 | C/VV |
| Ψ_{JB} | Junction-to-board characterization parameter | 36 | |
| R _{0JC(bot)} | Junction-to-case (bottom) thermal resistance | 12.8 | |

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

7.5 Electrical Characteristics: V_{BIAS} = 5 V

Unless otherwise noted, the specification in the following table applies over the operating ambient temperature $-40^{\circ}C \le T_A \le 85^{\circ}C$ (Full) and $V_{BIAS} = 5$ V. Typical values are for $T_A = 25^{\circ}C$.

| | PARAMETER | TEST COND | ITIONS | TA | MIN TYP | MAX | UNIT |
|---------------------------|--|---|--------------------------|------|---------|-----|------|
| POWER SU | PPLIES AND CURRENTS | | | | | | |
| I _{IN(VBIAS-ON)} | V _{BIAS} quiescent current | $I_{OUT} = 0,$ $V_{IN} = V_{ON} = V_{BIAS} = 5 \text{ V}$ | | Full | 50 | 75 | μA |
| IIN(VBIAS-OFF) | V _{BIAS} shutdown current | $V_{ON} = GND, V_{OUT} = 0 V$ | | Full | | 2 | μA |
| | | | $V_{IN} = 5 V$ | _ | 0.2 | 8 | |
| | V _{IN} off-state supply current | V _{ON} = GND, | $V_{IN} = 3.3 V$ | Full | 0.02 | 3 | μA |
| I _{IN(VIN-OFF)} | VIN OII-State Supply current | $V_{OUT} = 0 V$ | $V_{IN} = 1.8 V$ | ruii | 0.01 | 2 | μΑ |
| | | | V _{IN} = 0.8 V | | 0.005 | 1 | |
| I _{ON} | ON pin input leakage current | V _{ON} = 5.5 V | | Full | | 0.5 | μA |
| RESISTANC | E CHARACTERISTICS | | | | | | |
| | | | V _{IN} = 5 V | 25°C | 22 | 33 | |
| | | | v _{IN} = 5 v | Full | | 35 | |
| | | | V _{IN} = 3.3 V | 25°C | 22 | 33 | |
| | | | v _{IN} = 3.3 v | Full | | 35 | |
| | | | V _ 1 Q V | 25°C | 22 | 33 | |
| Р | ON-state resistance | I _{OUT} = -200 mA, | V _{IN} = 1.8 V | Full | | 35 | mΩ |
| R _{ON} | ON-state resistance | $V_{BIAS} = 5 V$ | | 25°C | 22 | 33 | |
| | | | V _{IN} = 1.5 V | Full | | 35 | |
| | | | V 10V | 25°C | 22 | 33 | |
| | | | V _{IN} = 1.2 V | Full | | 35 | |
| | | | $\lambda = 0.8 \lambda $ | 25°C | 22 | 33 | |
| | | | V _{IN} = 0.8 V | Full | | 35 | |
| R _{PD} | Output pulldown resistance | V _{IN} = 5.0 V, V _{ON} = 0V, I ₀ | _{OUT} = 15 mA | Full | 225 | 300 | Ω |

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7.6 Electrical Characteristics: V_{BIAS} = 2.5 V

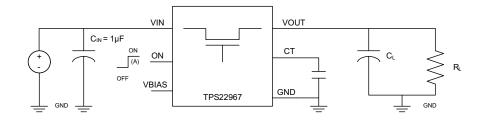
Unless otherwise noted, the specification in the following table applies over the operating ambient temperature $-40^{\circ}C \le T_A \le 85^{\circ}C$ (Full) and $V_{BIAS} = 2.5$ V. Typical values are for $T_A = 25^{\circ}C$.

| | PARAMETER | TEST CON | DITIONS | TA | MIN TYP | MAX | UNIT |
|---------------------------|--|--|--------------------------|---------|---------|-----|------|
| POWER SU | PPLIES AND CURRENTS | | | | | | |
| I _{IN(VBIAS-ON)} | V _{BIAS} quiescent current | $I_{OUT} = 0,$ $V_{IN} = V_{ON} = V_{BIAS} = 2.5$ | 5 V | Full | 20 | 30 | μA |
| IIN(VBIAS-OFF) | V _{BIAS} shutdown current | $V_{ON} = GND, V_{OUT} = 0$ | V | Full | | 2 | μA |
| | | | $V_{IN} = 2.5 V$ | | 0.01 | 3 | |
| | V off state supply surrant | V _{ON} = GND, | V _{IN} = 1.8 V | | 0.01 | 2 | |
| I _{IN(VIN-OFF)} | V _{IN} off-state supply current | $V_{OUT} = 0 V$ | V _{IN} = 1.2 V | Full | 0.005 | 2 | μA |
| | | | V _{IN} = 0.8 V | | 0.003 | 1 | |
| I _{ON} | ON pin input leakage current | V _{ON} = 5.5 V | · · · | Full | | 0.5 | μA |
| RESISTANC | E CHARACTERISTICS | | | | | · | |
| | | | | 25°C | 26 | 38 | |
| | | | V _{IN} = 2.5 V | Full | | 40 | |
| | | | V 40V | 25°C | 26 | 38 | |
| | | | V _{IN} = 1.8 V | Full | | 40 | |
| D | | I _{OUT} = -200 mA, | | 25°C | 25 | 38 | 0 |
| R _{ON} | ON-state resistance | $V_{BIAS} = 2.5 V$ | V _{IN} = 1.5 V | Full | | 40 | mΩ |
| | | | | 25°C | 24 | 38 | |
| | | | V _{IN} = 1.2 V | Full | | 40 | |
| | | | | 25°C | 24 | 38 | |
| | | | V _{IN} = 0.8 V | | | 40 | |
| R _{PD} | Output pulldown resistance | V _{IN} = 2.5 V, V _{ON} = 0 V, | $I_{OUT} = 1 \text{ mA}$ | Full | 275 | 325 | Ω |

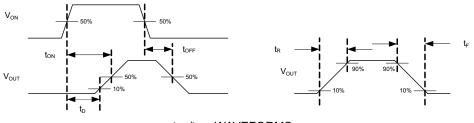


7.7 Switching Characteristics

| | PARAMETER | TEST CONDITIONS | MIN TYP | MAX | UNIT |
|---------------------|--|---|---------|-----|------|
| V _{IN} = V | V _{ON} = V _{BIAS} = 5 V, T _A = 25⁰C (U | NLESS OTHERWISE NOTED) | | | |
| t _{ON} | Turnon time | | 1325 | | |
| t _{OFF} | Turnoff time | | 10 | | |
| t _R | V _{OUT} rise time | $R_L = 10 \ \Omega, \ C_L = 0.1 \ \mu F, \ C_T = 1000 \ pF$ | 1625 | | μs |
| t _F | V _{OUT} fall time | | 3.5 | | |
| t _D | ON delay time | | 500 | | |
| $V_{IN} = 0$ | $0.8 \text{ V}, \text{ V}_{ON} = \text{V}_{BIAS} = 5 \text{ V}, \text{ T}_{A} = 2$ | 5ºC (UNLESS OTHERWISE NOTED) | | | |
| t _{ON} | Turnon time | | 600 | | |
| t _{OFF} | Turnoff time | | 80 | | |
| t _R | V _{OUT} rise time | $R_L = 10 \ \Omega, \ C_L = 0.1 \ \mu F, \ C_T = 1000 \ pF$ | 300 | | μs |
| t _F | V _{OUT} fall time | _ | 5.5 | | |
| t _D | ON delay time | | 460 | | |
| $V_{IN} = 2$ | $2.5 \text{ V}, \text{ V}_{ON} = 5 \text{ V}, \text{ V}_{BIAS} = 2.5 \text{ V},$ | T _A = 25°C (UNLESS OTHERWISE NOTED) | | | |
| t _{ON} | Turnon time | - | 2200 | | |
| t _{OFF} | Turnoff time | _ | 9 | | |
| t _R | V _{OUT} rise time | $R_L = 10 \ \Omega, \ C_L = 0.1 \ \mu F, \ C_T = 1000 \ pF$ | 2275 | | μs |
| t _F | V _{OUT} fall time | _ | 3.1 | | |
| t _D | ON delay time | | 1075 | | |
| $V_{IN} = 0$ | $0.8 \text{ V}, \text{ V}_{ON} = 5 \text{ V}, \text{ V}_{BIAS} = 2.5 \text{ V},$ | T _A = 25°C (UNLESS OTHERWISE NOTED) | | | |
| t _{ON} | Turn-on time | _ | 1450 | | |
| t _{OFF} | Turn-off time | _ | 60 | | |
| t _R | V _{OUT} rise time | $R_L = 10 \ \Omega, \ C_L = 0.1 \ \mu F, \ C_T = 1000 \ pF$ | 875 | | μs |
| t _F | V _{OUT} fall time | _ | 5.5 | | |
| t _D | ON delay time | | 1010 | | |



TEST CIRCUIT



 $t_{\text{ON}}/t_{\text{OFF}}$ WAVEFORMS

(A) Rise and fall times of the control signal is 100ns.

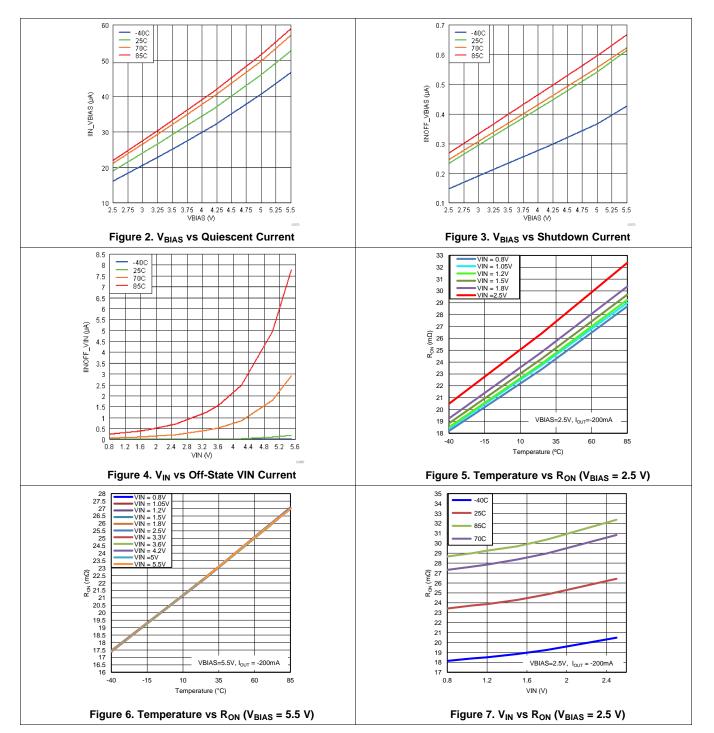
Figure 1. Test Circuit and Timing Waveforms

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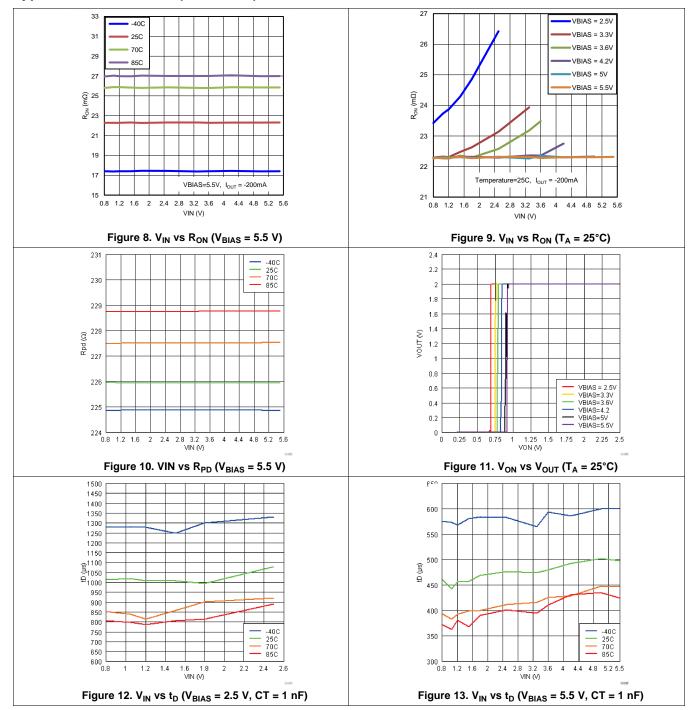
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7.8 Typical Characteristics



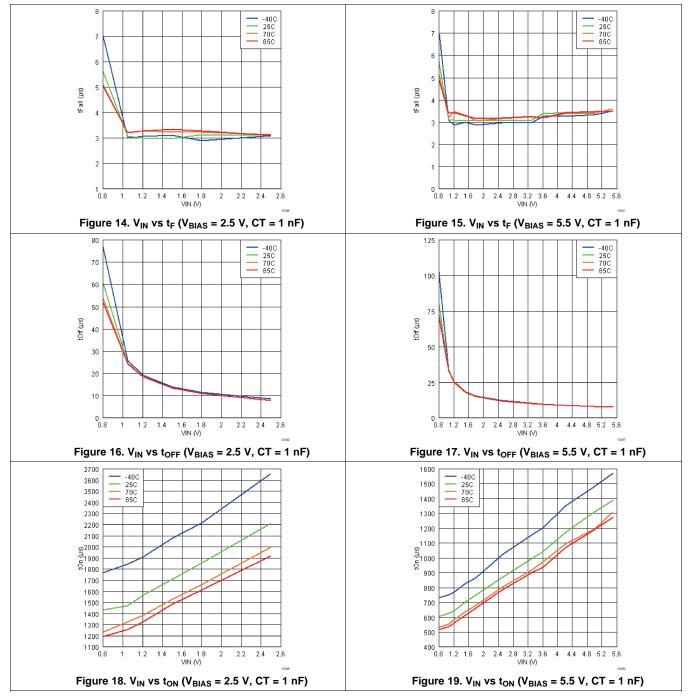


Typical Characteristics (continued)



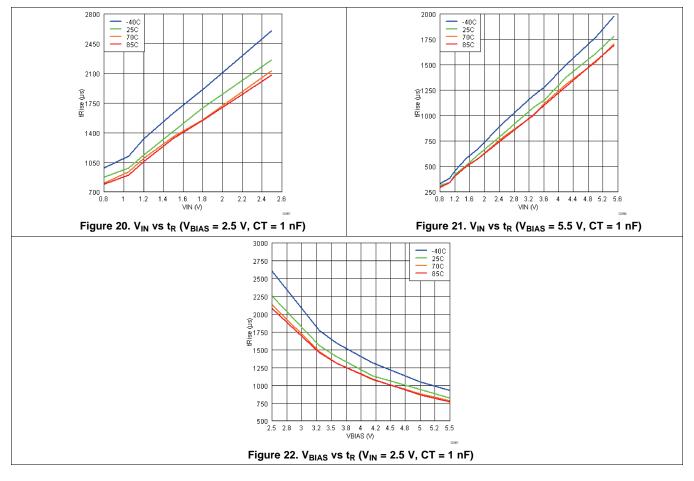


Typical Characteristics (continued)





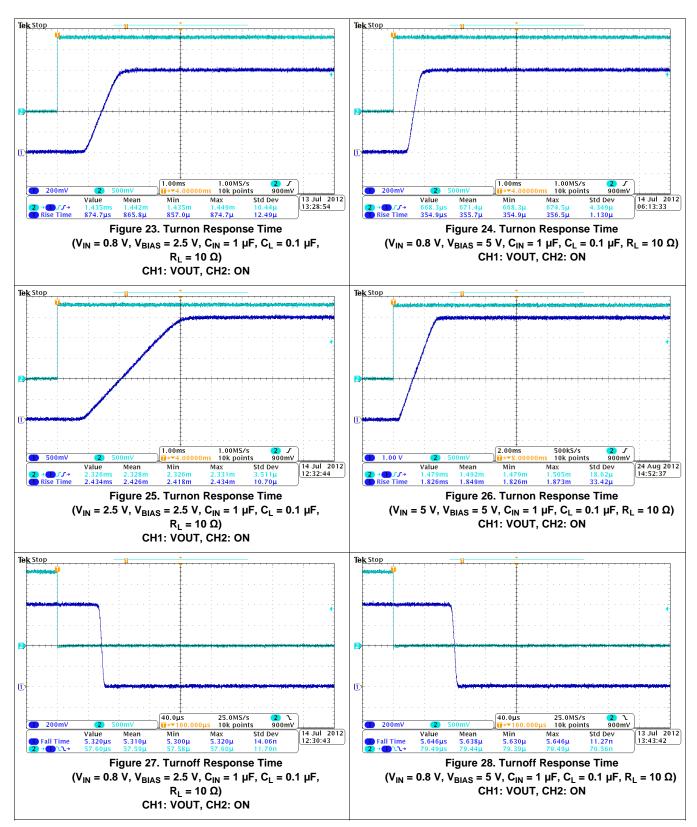
Typical Characteristics (continued)



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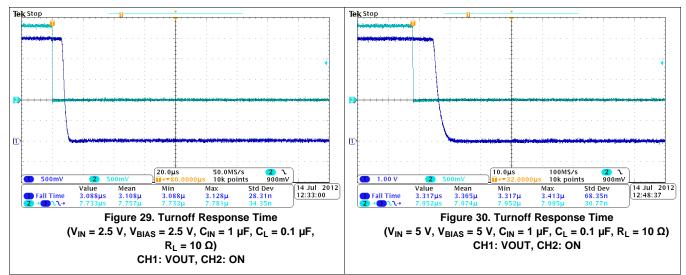
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7.8.1 Typical AC Scope Captures at $T_A = 25^{\circ}C$, CT = 1 nF





Typical AC Scope Captures at $T_A = 25^{\circ}C$, CT = 1 nF (continued)





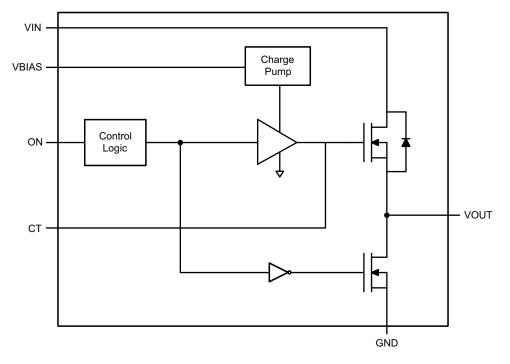
8 Detailed Description

8.1 Overview

The TPS22967 device is a single-channel, 4-A load switch in an 8-pin WSON package. To reduce the voltage drop in high current rails, the device implements an ultra-low resistance N-channel MOSFET. The device has a programmable slew rate for applications that require specific rise time.

The device has very low leakage current during off state. This prevents downstream circuits from pulling high standby current from the supply. Integrated control logic, driver, power supply, and output discharge FET eliminates the need for any external components, which reduces solution size and bill of materials (BOM) count.

8.2 Functional Block Diagram



8.3 Feature Description

This section describes the integrated features for the TPS22967.

8.3.1 ON/OFF Control

The ON pin controls the state of the switch. Asserting ON high enables the switch. ON is active high and has a low threshold, making it capable of interfacing with low-voltage signals. The ON pin is compatible with standard GPIO logic thresholds. It can be used with any microcontroller with 1.2 V or higher GPIO voltage. This pin cannot be left floating and must be driven either high or low for proper functionality.



Feature Description (continued)

8.3.2 Adjustable Rise Time

(1)

A capacitor to GND on the CT pin sets the VOUT slew rate. The voltage on the CT pin can be as high as 12 V. Therefore, the minimum voltage rating for the CT capacitor must be 25 V for optimal performance. An approximate formula for the relationship between CT and slew rate is (Equation 1 accounts for 10% to 90% measurement on V_{OUT} and does NOT apply for CT = 0 pF. Use Table 1 to determine rise times for when CT = 0 pF):

 $SR=0.39\times CT+13.4$

where

- SR = slew rate (in μ s/V).
- CT = the capacitance value on the CT pin (in pF).
- The units for the constant 13.4 is in μ s/V. The units for the constant 0.39 are in μ s/(V × pF).

Rise time can be calculated by multiplying the input voltage by the slew rate. Table 1 contains rise time values measured on a typical device. Rise times shown below are only valid for the power-up sequence where V_{IN} and V_{BIAS} are already in steady state condition, and the ON pin is asserted high.

| CTx (pF) | RISE TIME (μs) 10% - 90%, C _L = 0.1 μF, C _{IN} = 1 μF, R _L = 10 Ω TYPICAL VALUES at 25°C, 25 V X7R 10% CERAMIC CAPACITOR | | | | | | | |
|----------|--|-------|-------|-------|-------|--------|-------|--|
| | 5 V | 3.3 V | 1.8 V | 1.5 V | 1.2 V | 1.05 V | 0.8 V | |
| 0 | 127 | 93 | 62 | 55 | 51 | 46 | 42 | |
| 220 | 475 | 314 | 188 | 162 | 141 | 125 | 103 | |
| 470 | 939 | 637 | 359 | 304 | 255 | 218 | 188 | |
| 1000 | 1869 | 1229 | 684 | 567 | 476 | 414 | 344 | |
| 2200 | 4020 | 2614 | 1469 | 1211 | 1024 | 876 | 681 | |
| 4700 | 8690 | 5746 | 3167 | 2703 | 2139 | 1877 | 1568 | |
| 10000 | 18360 | 12550 | 6849 | 5836 | 4782 | 4089 | 3449 | |

Table 1. Rise Times On a Typical Device

8.3.3 Quick Output Discharge

The TPS22967 includes a Quick Output Discharge (QOD) feature. When the switch is disabled, a discharge resistor is connected between VOUT and GND. This resistor has a typical value of 225 Ω and prevents the output from floating while the switch is disabled.

8.4 Device Functional Modes

Table 2 describes the functional state of the load switch as determined by the ON pin.

Table 2. Functional Table

| ON | VIN to VOUT | VOUT to GND |
|----|-------------|-------------|
| L | Off | On |
| Н | On | Off |

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

This section describes design considerations for the TPS22967 which can vary depending on the specific application.

9.1.1 Input Capacitor (Optional)

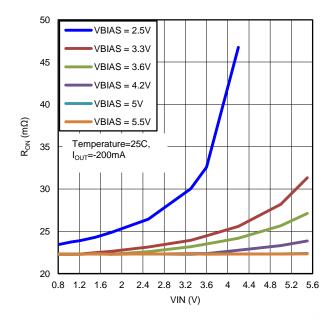
To limit the voltage drop on the input supply caused by transient inrush currents when the switch turns on into a discharged load capacitor or short circuit, a capacitor must be placed between VIN and GND. A 1- μ F ceramic capacitor, C_{IN}, placed close to the pins, is usually sufficient. Higher values of C_{IN} can be used to further reduce the voltage drop during high-current applications. When switching heavy loads, TI recommends having an input capacitor about 10 times higher than the output capacitor to avoid excessive voltage drop.

9.1.2 Output Capacitor (Optional)

Because of the integrated body diode in the NMOS switch, a C_{IN} greater than C_L is highly recommended. A C_L greater than C_{IN} can cause V_{OUT} to exceed V_{IN} when the system supply is removed. This could result in current flow through the body diode from VOUT to VIN. A C_{IN} to C_L ratio of 10 to 1 is recommended for minimizing V_{IN} dip caused by inrush currents during start-up; however, a 10-to-1 ratio for capacitance is not required for proper functionality of the device. A ratio smaller than 10 to 1 (such as 1 to 1) could cause slightly more V_{IN} dip upon turnon due to inrush currents. This can be mitigated by increasing the capacitance on the CT pin for a longer rise time (see below).

9.1.3 V_{IN} and V_{BIAS} Voltage Range

For optimal R_{ON} performance, make sure $V_{IN} \le V_{BIAS}$. The device will still be functional if $V_{IN} > V_{BIAS}$ but it will exhibit R_{ON} greater than what is listed in the *Electrical Characteristics:* $V_{BIAS} = 5 V$ table. See Figure 31 for an example of a typical device. Notice the increasing R_{ON} as V_{IN} exceeds V_{BIAS} voltage. Never exceed the maximum voltage rating for VIN and VBIAS.



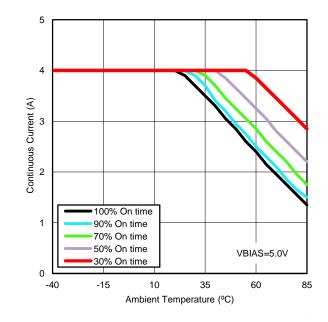




Application Information (continued)

9.1.4 Safe Operating Area (SOA)

The SOA curves show the continuous current carrying capability of the device versus ambient temperature (T_A) to ensure reliable operation over 70,000 hours of device lifetime. The different curves represent the *percentage On time* over device lifetime and can be used as a reference to understand the current carrying capability of TPS22967 under different use cases. TI recommends maintaining continuous current at or below the SOA curves shown in Figure 32.



On time is the duration of time that the device is enabled (ON \ge V_{IH}) over 70,000 hour lifetime.

Figure 32. Safe Operating Area

9.2 Typical Application

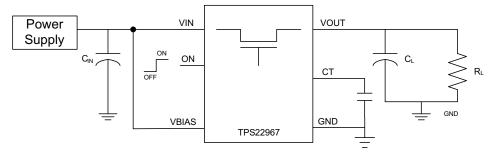


Figure 33. Typical Application Schematic



(2)

(3)

(4)

Typical Application (continued)

9.2.1 Design Requirements

For this design example, use the parameters listed in Table 3 as the input parameters.

| DESIGN PARAMETER | EXAMPLE VALUE | | | | | | |
|-----------------------------------|---------------|--|--|--|--|--|--|
| V _{IN} | 3.3 V | | | | | | |
| V _{BIAS} | 5 V | | | | | | |
| CL | 22 µF | | | | | | |
| Maximum Acceptable Inrush Current | 400 mA | | | | | | |

Table 3. Design Parameters

9.2.2 Detailed Design Procedure

9.2.2.1 Inrush Current

When the switch is enabled, the output capacitors must be charged up from 0 V to the set value (3.3 V in this example). This charge arrives in the form of inrush current. Inrush current can be calculated using Equation 2: Inrush Current = $C \times dV/dt$

where

- C = output capacitance.
- dV = output voltage.
- dt = rise time.

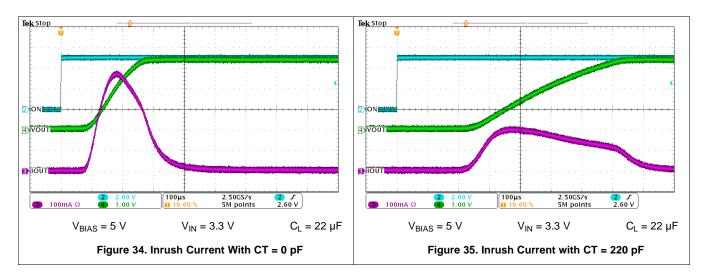
The TPS22967 offers adjustable rise time for VOUT. This feature lets the user control the inrush current during turnon. The appropriate rise time can be calculated using the design requirements and the inrush current equation.

400 mA = 22 µ F × 3.3 V/dt

dt = 181.5 µs

To ensure an inrush current of less than 400 mA, choose a CT value that will yield a rise time of more than 181.5 µs. See *Application Curves* for an example of how the CT capacitor can be used to reduce inrush current.

9.2.3 Application Curves





10 Power Supply Recommendations

The device is designed to operate from a VBIAS range of 2.5 V to 5.5 V and a VIN range of 0.8 V to 5.5 V. The power supply must be well regulated and placed as close to the device terminals as possible. It must be able to withstand all transient and load current steps. In most situations, using an input capacitance of 1 μ F is sufficient to prevent the supply voltage from dipping when the switch is turned on. In cases where the power supply is slow to respond to a large transient current or large load current step, additional bulk capacitance may be required on the input.

The requirements for larger input capacitance can be mitigated by adding additional capacitance to the CT pin. This additional capacitance causes the load switch to turn on more slowly. Not only will this reduce transient inrush current, but it will also give the power supply more time to respond to the load current step.

11 Layout

11.1 Layout Guidelines

For best performance, all traces must be as short as possible. To be most effective, the input and output capacitors must be placed close to the device to minimize the effects that parasitic trace inductances may have on normal operation. Using wide traces for VIN, VOUT, and GND helps minimize the parasitic electrical effects along with minimizing the case to ambient thermal impedance.

The maximum IC junction temperature must be restricted to 125°C under normal operating conditions. To calculate the maximum allowable dissipation, $P_{D(max)}$ for a given output current and ambient temperature, use Equation 5 as a guideline:

$$P_{D(max)} = \frac{T_{J(max)} - T_{A}}{\theta_{JA}}$$

where

- P_{D(max)} = maximum allowable power dissipation.
- T_{J(max)} = maximum allowable junction temperature (125°C for the TPS22967).
- T_A = ambient temperature of the device.
- Θ_{JA} = junction to air thermal impedance. See *Thermal Information*. This parameter is highly dependent upon board layout. (5)

Figure 36 shows an example of a layout. Notice the thermal vias under the exposed thermal pad of the device. This allows for thermal diffusion away from the device.



11.2 Layout Example

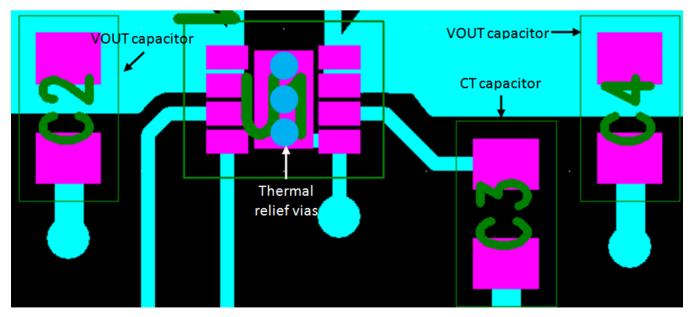


Figure 36. Layout Example

12 Device and Documentation Support

12.1 Trademarks

Ultrabooks is a trademark of Intel. All other trademarks are the property of their respective owners.

12.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



21-Feb-2015

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package | Pins | Package | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|---------|----------------------------|------------------|---------------------|--------------|----------------|---------|
| | (1) | | Drawing | | Qty | (2) | (6) | (3) | | (4/5) | |
| TPS22967DSGR | ACTIVE | WSON | DSG | 8 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | ZTU | Samples |
| TPS22967DSGT | ACTIVE | WSON | DSG | 8 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | ZTU | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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21-Feb-2015

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nominal | | | | | | | | | | | | |
|-----------------------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| TPS22967DSGR | WSON | DSG | 8 | 3000 | 180.0 | 8.4 | 2.3 | 2.3 | 1.15 | 4.0 | 8.0 | Q2 |
| TPS22967DSGT | WSON | DSG | 8 | 250 | 180.0 | 8.4 | 2.3 | 2.3 | 1.15 | 4.0 | 8.0 | Q2 |

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

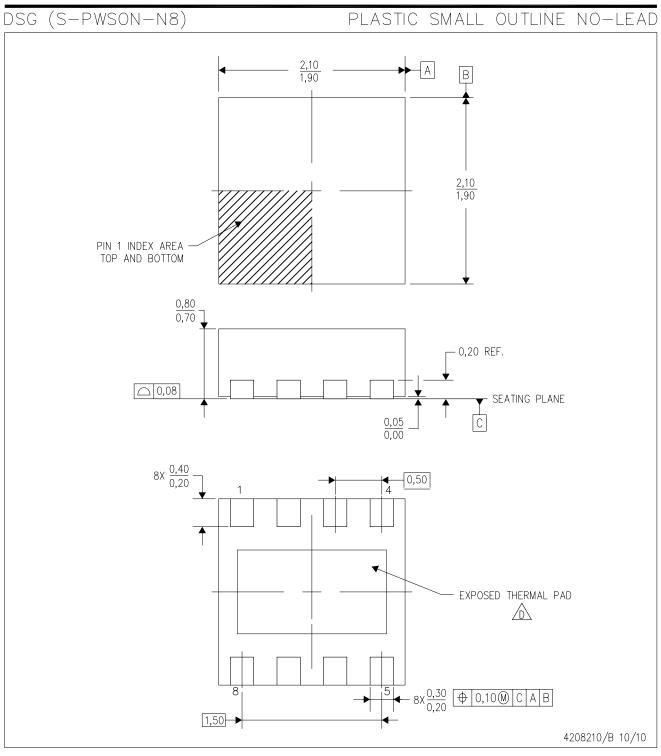
10-Jul-2015



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS22967DSGR | WSON | DSG | 8 | 3000 | 210.0 | 185.0 | 35.0 |
| TPS22967DSGT | WSON | DSG | 8 | 250 | 210.0 | 185.0 | 35.0 |

MECHANICAL DATA



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No-Leads (QFN) package configuration.

The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.

E. Falls within JEDEC MO-229.



DSG (S-PWSON-N8)

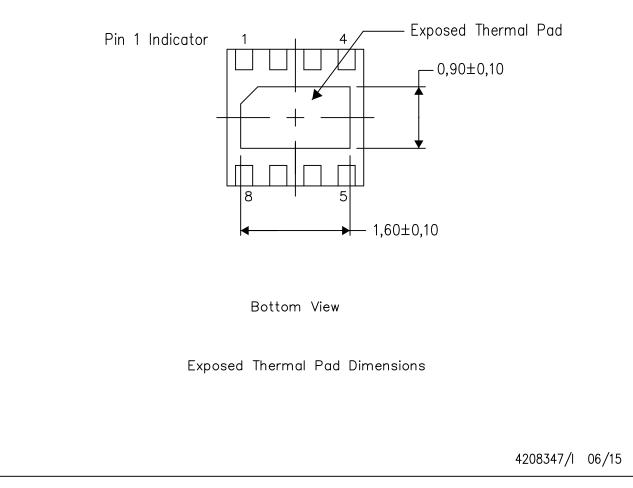
PLASTIC SMALL OUTLINE NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

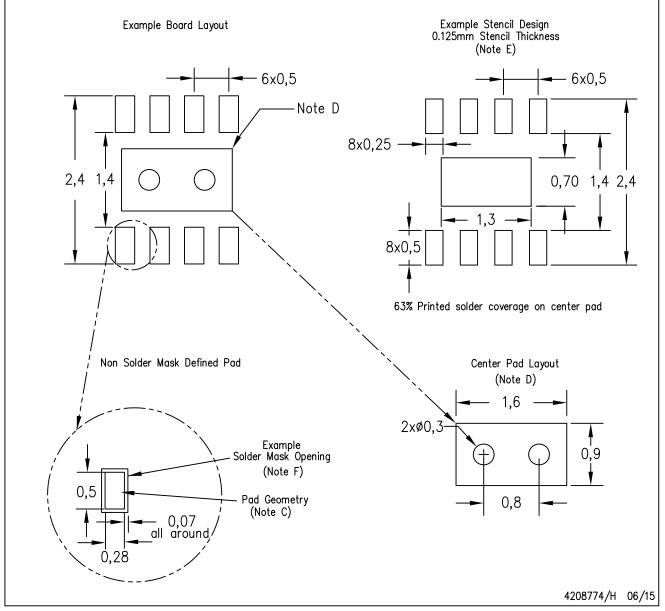


NOTE: All linear dimensions are in millimeters



DSG (S-PWSON-N8)

PLASTIC SMALL OUTLINE NO-LEAD



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for solder mask tolerances.



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